

Revision 0.90

## **SINGLE FREQUENCY LASER DIODES Distributed Feedback Laser**



### General Product Information

Product	Application
795 nm DFB Laser	Spectroscopy (Rb D1 line)
with hermetic 14-Pin Butterfly Housing (RoHS compliant)	Metrology
including Monitor Diode, Thermoelectric Cooler and Thermistor	
with integrated μ-Isolator and Beam Collimation	



### Absolute Maximum Ratings

Parameter	Symbol	Unit	min	typ	max
Storage Temperature	T <sub>S</sub>	°C	-40		85
Operational Temperature at Case	$T_{C}$	°C	-40		85
Operational Temperature at Laser Chip	$T_LD$	°C	10		50
Forward Current	I <sub>F</sub>	mA			170
Reverse Voltage	$V_R$	V			2
Output Power	$P_{opt}$	mW			45
TEC Current	$I_{TEC}$	Α			1.1
TEC Voltage	$V_{TEC}$	V			2.8

#### **Measurement Conditions / Comments**

Stress in excess of one of the Absolute Maximum Ratings may damage the laser. Please note that a damaging optical power level may occur although the maximum current is not reached. These are stress ratings only, and functional operation at these or any other conditions beyond those indicated under Recommended Operational Conditions is not implied.

### Recommended Operational Conditions

Parameter	Symbol	Unit	min	typ	max
Operational Temperature at Case	$T_{case}$	°C	-20		65
Operational Temperature at Laser Chip	$T_{LD}$	°C	15		45
Forward Current	I <sub>F</sub>	mA			160
Output Power	$P_{\text{opt}}$	mW	10		40

Measurement Conditions / Comments
measured by integrated Thermistor

### Characteristics at T<sub>LD</sub> = 25° at BOL

Parameter	Symbol	Unit	min	typ	max
Center Wavelength	$\lambda_{C}$	nm	794	795	796
Target Wavelength	$\lambda_{T}$	nm		794.98	
Linewidth (FWHM)	Δλ	MHz		0.6	1.0
Mode-hop free Tuning Range	$\Delta \lambda_{\text{tune}}$	pm	25		
Sidemode Supression Ratio	SMSR	dB	30	45	



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Characteristics at T <sub>LD</sub> = 25° at	BOL				cont'd
Parameter	Symbol	Unit	min	typ	max
Temperature Coefficient of Wavelength	dλ / dT	nm / K		0.06	
Current Coefficient of Wavelength	dλ / dl	nm / mA		0.003	
Laser Current @ P <sub>opt</sub> = 40 mW	$I_{LD}$	mA			160
Slope Efficiency	η	W/A	0.3	0.4	0.6
Threshold Current	$I_{th}$	mA			70
Divergence parallel (FWHM)	$\Theta_{  }$	0		0.1	
Divergence perpendicular (FWHM)	$\Theta_{\perp}$	0		0.1	
Beam Diameter horizontal	d	mm		1.0	1.2
Beam Diameter vertical	$d_\perp$	mm		0.8	1.2
Degree of Polarization	DOP	%		99	

Measurement Conditions / Comments
parallel to the base plate of the housing (see p. 3)
perpendicular to base plate of the housing (see p. 3)
parallel to the base plate of the housing (see p. 3)
perpendicular to base plate of the housing (see p. 3)
P <sub>opt</sub> = 40 mW; slant polarization (45°); see p.3

Monitor Diode					
Parameter	Symbol	Unit	min	typ	max
Monitor Detector Responsivity	I <sub>mon</sub> / P <sub>opt</sub>	μA/mW	1		20

	Meası	urement Conditions / Comments
$U_R = 5 V$	$U_R =$	5 V

Parameter	Symbol	Unit	min	typ	max
Current	I <sub>TEC</sub>	А		0.4	
Voltage	$U_TEC$	V		1.3	
Power Dissipation (total loss at case)	P <sub>loss</sub>	W		0.4	
Temperature Difference	ΔΤ	K			50

Measurement Cor	nditions / Comments
$P_{\rm opt} = 40 \text{ mW, } \Delta T$	= 20 K
$P_{opt} = 40 \text{ mW, } \Delta T$	= 20 K
$P_{opt} = 40 \text{ mW, } \Delta T$	= 20 K
$P_{opt} = 40 \text{ mW, } \Delta T$	=  Tcase - TLD

Thermistor (Standard NTC Type)					
Parameter	Symbol	Unit	min	typ	max
Resistance	R	kΩ		10	
Beta Coefficient	β			3892	
Steinhart & Hart Coefficient A	А		1.1293 x 10 <sup>-3</sup>		
Steinhart & Hart Coefficient B	В		2.3410 x 10 <sup>-4</sup>		
Steinhart & Hart Coefficient C	C		8.7755 x 10 <sup>-8</sup>		

Measurement Conditions / Comments					
$T_{LD} = 25^{\circ} C$					
$R_1  /  R_2 = e^{ \beta  (1/T_1  -  1/T_2)} $ at $T_{LD} =$	0° 50° C				
$1/T = A + B(\ln R) + C(\ln R)^3$					
T: temperature in Kelvin					
R: resistance at T in Ohm					



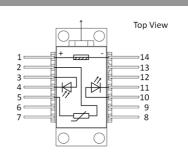
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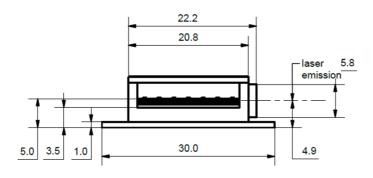


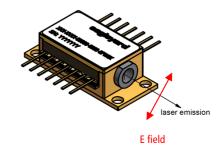
## Pin Assignment

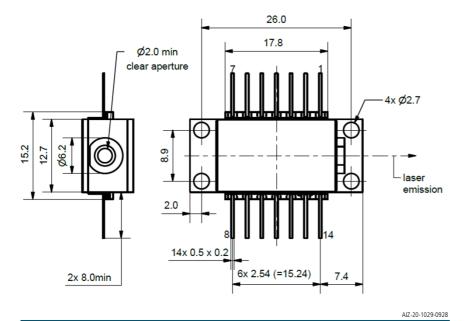
1	Thermoelectric Cooler (+)	14	Thermoelectric Cooler (-)
2	Thermistor	13	Case
3	Photodiode (Anode)	12	not connected
4	Photodiode (Cathode)	11	Laser Diode (Cathode)
5	Thermistor	10	Laser Diode (Anode)
6	not connected	9	not connected
7	not connected	8	not connected



## Package Drawings







Caution. Excessive mechanical stress on the package can lead to a damage of the laser.

See <u>instruction manual</u> on www.eagleyard.com



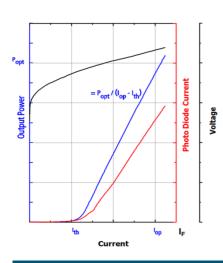
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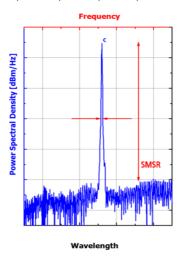


#### Typical Measurement Results

Output Power vs. Current



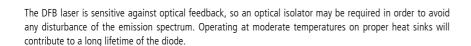
Spectra at Specified Optical Output Power



Performance figures, data and any illustrative material provided in this specification are typical and must be specifically confirmed in writing by eagleyard Photonics before they become applicable to any particular order or contract. In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.

#### Unpacking, Installation and Laser Safety

Unpacking the laser diodes should only be done at electrostatic safe workstations (EPA). Though protection against electro static discharge (ESD) is implemented in the laser package, charges may occur at surfaces. Please store this product in its original package at a dry, clean place until final use. During device installation, ESD protection has to be maintained.



Avoid direct and/or indirect exposure to the free running beam. Collimating and focussing the free running beam with optics as common in optical instruments will increase threat to the human eye.

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Laser Emission





INVISIBLE LASER RADIATION
AVOID EYE OR SKIN EXPOSURE
TO DIRECT OR SCATTERED RADIATION
CLASS 4 LASER PRODUCT
WAVELENGTH 795 nm
MAX. OUTPUT POWER 45 mW



